

### NAU82011WG 2.9 W Mono Filter-Free Class-D Audio Amplifier

### 1 Description

The NAU82011WG is a mono high efficiency filter-free Class-D audio amplifier with variable gain, which is capable of driving a  $4\Omega$  load with up to 2.9W output power. This device provides chip enable pin with extremely low standby current and fast start-up time of 4ms.

The NAU82011WG is ideal for the portable applications of battery drive, as it has advanced features like 91% efficiency, low quiescent current (i.e. 1.2mA at 3.6V) and superior EMI performance. It has the ability to configure the inputs in either single-ended or differential mode.

NAU82011WG is available in MSOP-8 package.

#### **Key Features**

- Low Quiescent Current:
  - 1.2mA at 3.6V
  - 1.7mA at 5V
- Powerful Mono Class-D Amplifier:
  - 2.9W (4Ω @ 5V, 10% THD+N)
  - 2.3W (4Ω @ 5V, 1% THD+N)
  - 1.7W (8 $\Omega$  @ 5V, 10% THD+N)
  - 1.38W (8Ω @ 5V, 1% THD+N)
- Low Output Noise: 20 μV<sub>RMS</sub>
- Low Current Shutdown Mode
- Integrated Image Reject Filter
- Click-and Pop Suppression
- Integrated feedback resistor of 300 kΩ

- 1.48 W (4Ω @ 3.6V, 10% THD+N)
- 1.2 W (4 $\Omega$  @ 3.6V, 1% THD+N)
- 0.88 W (8Ω @ 3.6V, 10% THD+N)
- 0.71 W (8 $\Omega$  @ 3.6V, 1% THD+N)

#### **Applications**

- Smartphones
- Tablet PCs
- Personal Navigation Devices

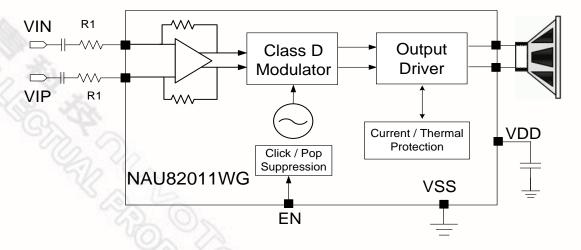
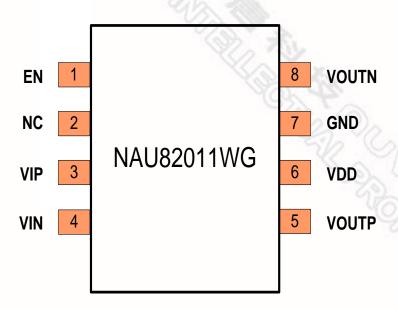


Figure 1: NAU82011WG Block Diagram



### 2 Pin out



	Part Number	Dimension	Package	Package Material
-	NAU82011WG	3mm x 3mm	MSOP-8	Green

# 3 Pin Descriptions

Pin#	Name	Туре	Functionality
1	EN	Digital Input	Chip Enable (High = Power Up; Low = Power Down)
2	NC	NC	No Connection
3	VIP	Analog Input	Positive Differential Input
4	VIN	Analog Input	Negative Differential Input
5	VOUTP	Analog Output	Positive BTL Output
6	VDD	Supply	Power Supply
7	GND	Supply	High Current Ground
8	VOUTN	Analog Output	Negative BTL Output

Table 1: NAU82011WG Pin description



### **Electrical Characteristics**

Conditions: EN = VDD = 5V, VSS = 0V, Av = 6dB,  $Z_L$  =  $\infty$ , unless otherwise specified, R1 = 150k $\Omega$ , Bandwidth = 20Hz to 22 kHz,  $T_A$  = 25  $^{\rm o}C$ 

Parameter	Symbol	Comments/Conditions		Min	Тур	Max	Units
Power Delivered			1/2/2	1000			
		$Z_L = 4\Omega + 33\mu H$	VDD = 5.0V		2.9		
	$P_{out}$	THD + N = 10%	VDD = 3.6V	03	1.48		
		$Z_L = 4\Omega + 33\mu H$	VDD = 5.0V		2.3		
Output Power		THD + N = 1%	VDD = 3.6V	1000	1.2		$\exists$ w
		$Z_L = 8\Omega + 68\mu H$	VDD = 5.0V	763	1.7		T vv
		THD + N = 10%	VDD = 3.6V	- 7	0.88	2)	
		$Z_L = 8\Omega + 68\mu H$	VDD = 5.0V		1.38	4/2	
		THD + N = 1%	VDD = 3.6V		0.71	100	

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units		
Chip Enable (EN)								
Voltage Enable High	V <sub>EN H</sub>	VDD = 2.5V  to  5.5V	1.3			V		
Voltage Enable Low	V <sub>EN L</sub>	VDD = 2.5V  to  5.5V			0.35	V		
Input Leakage Current				0.1	2.0	μA		
Thermal and Current Protection								
Thermal Shutdown Temp				150		°C		
Thermal Shutdown Hysteresis				20		°C		
Over Current Threshold	$I_{OC}$			2.0		A		
Gain	$A_{V}$	VDD = 2.5V  to  5.5V, R1	255/R1	300/R1	345/R1	V/V		
2000		in kΩ						
Resistance (EN pin to GND)	$R_{EN}$			300		kΩ		



### **Electrical Characteristics (continued)**

Conditions: EN = VDD = 5V, VSS = 0V, Av = 6dB, R1 = 150k $\Omega$ , ZL =  $\infty$ , unless otherwise specified, Bandwidth = 20Hz to 22 kHz,  $T_A$  = 25  $^{\circ}C$ 

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units
Normal Operation		- V2A	11111			
Ovice and Cumont Consumntion	т	VDD = 3.6V	V 13	1.2		mA
Quiescent Current Consumption	$I_{QUI}$	VDD = 5V	03	1.7		mA
Shut Down Current	$I_{OFF}$	EN = 0		0.5		μA
Oscillator Frequency	$f_{OSC}$		1000	300		kHz
Efficiency	η	$RL = 8\Omega$	163	91		%
Start Up Time	$T_{start}$		1	4	201	msec
Output Offset Voltage	Vos			±1	4/3	mV
Common Mode Rejection Ratio	CMRR	$f_{IN} = 1kHz$		63	100	dB
Click-and-Pop Suppression		1Hz Shutdown (ZL=8Ω)		83	1	dBV
		DC PSRR		95	10/1	dB
Down Cumply Dejection Datio	PSRR	AC PSRR V <sub>RIPPLE</sub> =		60	92	dB
Power Supply Rejection Ratio	PSKK	0.2Vpp@1kHz			46	0
Noise Performance		$V_{DD} = 3.6V$ (A-weighted)		20		$\mu V_{RMS}$

### **Absolute Maximum Ratings**

Parameter	Min	Max	Units
Analog supply	-0.50	+5.50	V
Industrial operating temperature	-40	+85	°C
Storage temperature range	-65	+150	°C
Junction temperature range	-40	+150	°C

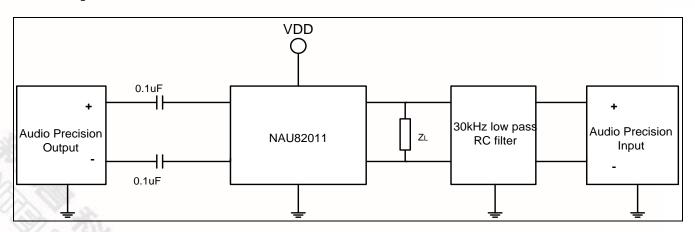
CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely influence product reliability and result in failures not covered by warranty.



### **Recommended Operating Conditions**

		1 / / \			
Parameter	Symbol	Min	Typical	Max	Units
Analog supply range	VDD	2.50	5.00	5.50	V
Ground	VSS	10	0		V
Input Resistor (Gain ≤ 26dB)	R1	15	4024	D_	kΩ
Common mode Input voltage range VDD = 2.5V to 5.5V and CMRR ≥ 49dB	V <sub>IC</sub>	0	Sile	VDD - 1.0	V

### **Test Set up**

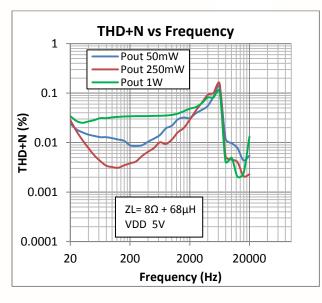


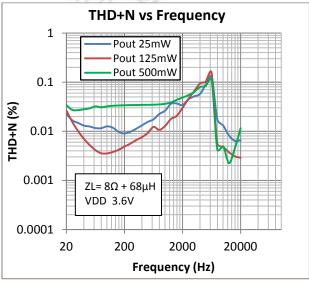
**Note:** The 30kHz low pass RC filter is implemented by using R = 1k Ohm and C = 4.7nF

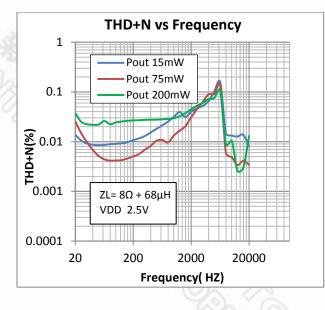


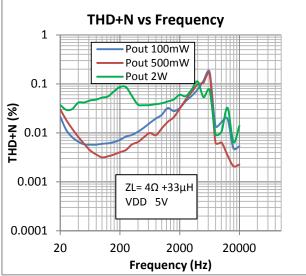
### 5 Typical Operating Characteristics

Conditions: EN =  $V_{DD}$  = 5V,  $V_{SS}$  = 0V, Av = 6dB (R1=150k $\Omega$ ),  $Z_L$  =  $\infty$ , unless otherwise specified, Bandwidth = 20Hz to 22 kHz,  $T_A$  = 25 °C, unless otherwise noted

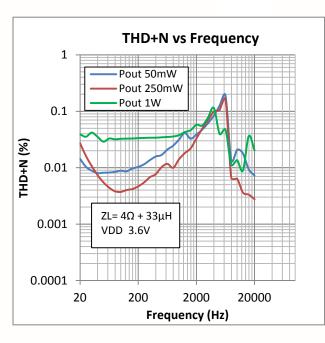


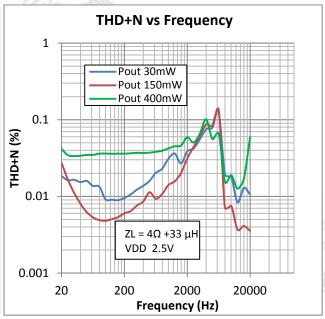


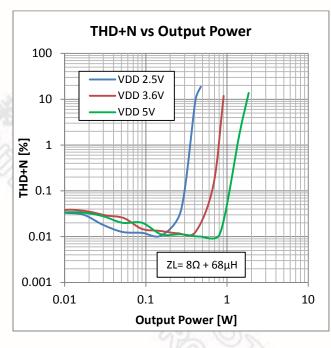


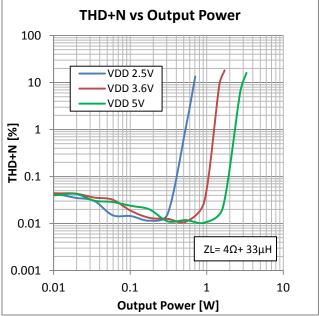




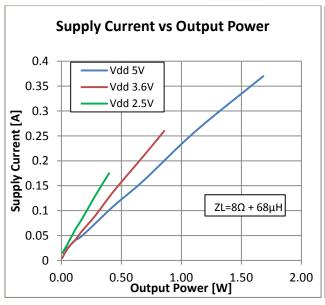


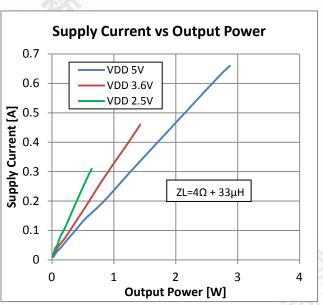


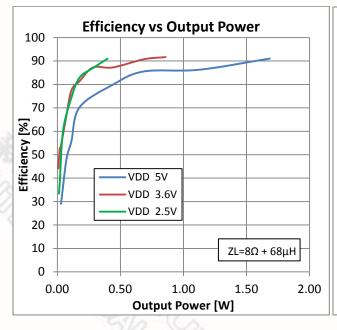


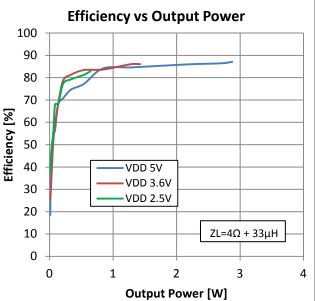




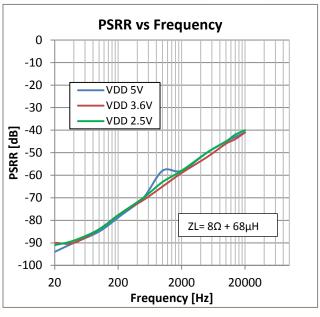


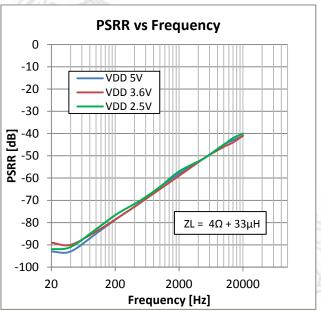


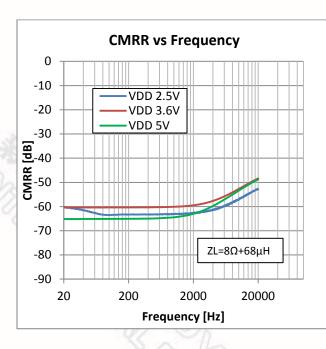


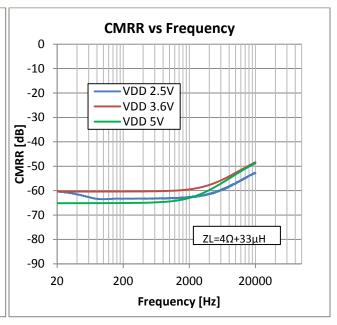












Note1: All the above plots are captured with 0.1uF input capacitor. It is recommended to use 2.2uF input capacitor to get a flat low frequency response.

Note2: The above PSRR plots are captured with input capacitors 2.2uF



### **6** Special Feature Description

The NAU82011WG offers excellent quantity performance as high efficiency, high output power and low quiescent current. It also provides the following special features.

#### 6.1 Device Protection

The NAU82011WG includes device protection for three operating scenarios. They are

- 1. Thermal Overload
- 2. Short circuit
- 3. Supply under voltage

#### **6.1.1 Thermal Overload Protection**

When the device internal junction temperature reaches 150°C, the NAU82011WG will disable the output drivers. When the device cools down and a safe operating temperature of 130°C has been reached for at least about 100ms, the output drivers will be enabled again.

#### **6.1.2** Short Circuit Protection

If a short circuit is detected on any of the pull-up or pull-down devices on the output drivers for at least  $16.7\mu s$ , the output drivers will be disabled for 100ms. The output drivers will then be enabled again and check for the short circuit. If the short circuit is still present, the output drivers are disabled after  $16.7\mu s$ . This cycle will continue until the short circuit is removed. The short circuit threshold is 2.0A at 3.6V.

#### **6.1.3** Supply under Voltage Protection

If the supply voltage drops under 2.1V, the output drivers will be disabled while the NAU82011WG control circuitry still operates. This will avoid the battery supply to drag down too low before the host processor can safely shut down the devices on the system. If the supply drops further below 1.6 V the internal power on reset is activated and puts the entire device in power down state.

#### 6.2 Power up and Power down Control

When the supply voltage ramps up, the internal power on reset circuit gets triggered. At this time all internal circuits will be set to power down state. The device can be enabled by setting the EN pin high. Upon setting the EN pin high, the device will go through an internal power up sequence in order to minimize 'pops' on the speaker output. The complete power up sequence will take about 4ms. The device will power down in about 30µs, when the EN pin is set low.

It is important to keep the input signal at zero amplitude in order to minimize the 'pops' when the EN pin is toggled.

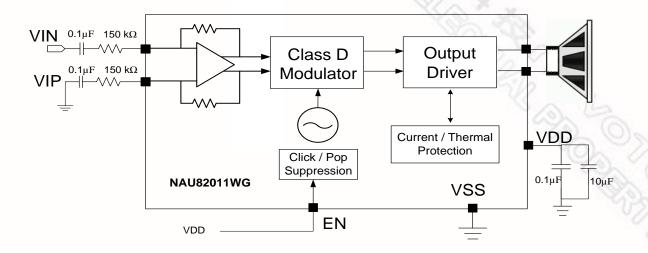
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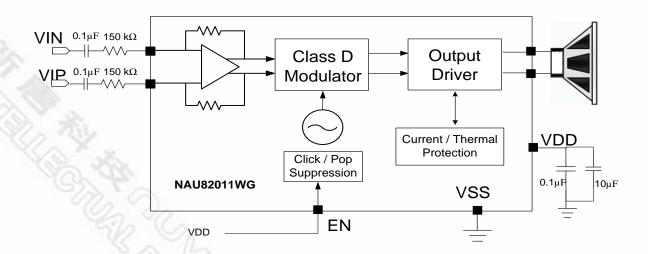
# 7 Application Information

### 7.1 Application diagram

### 7.1.1 Single ended input configuration



### 7.1.2 Differential input configuration





#### 7.2 Component selection

#### 7.2.1 Input resistors for Gain

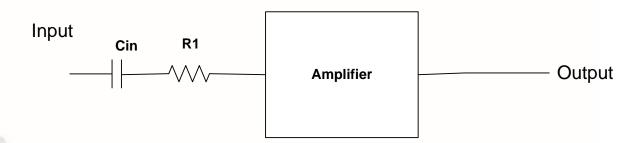
NAU82011WG has a provision for variable gain setting by using external input resistors. The gain is expressed as the ratio of the internal feedback resistor of  $300k\Omega$  and the external input resistor R. The Gain is expressed as

$$Gain = \frac{300 \, k\Omega}{R1 \, k\Omega} \left(\frac{V}{V}\right)$$
  $Gain (dB) = 20 \log \frac{300 \, k\Omega}{R1 \, k\Omega}$ 

### 7.2.2 Coupling Capacitors

An ac coupling capacitor (Cin) is used to block the dc content from the input source. The input resistance of the amplifier (R) together with the Cin will act as a high pass filter. So depending on the required cut off frequency the Cin can be calculated by using the following formula

 $Cin = 1/2\pi R1fc$  Where fc is the desired cut off frequency of the High pass filter.



### 7.2.3 Bypass Capacitors

Bypass capacitors are required to remove the ac ripple on the VDD pins. The value of these capacitors depends on the length of the VDD trace. In most cases, 10uF and 0.1uF are enough to get the good performance.

#### 7.3 Layout considerations

Good PCB layout and grounding techniques are essential to get the good audio performance. It is better to use low resistance traces as these devices are driving low impedance loads. The resistance of the traces has a significant effect on the output power delivered to the load. In order to dissipate more heat, use wide traces for the power and ground lines.

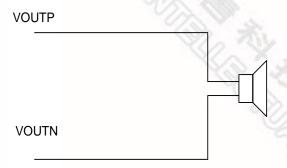
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#### 7.4 Class D without filter

The NAU82011WG is designed for use without any filter on the output line. That means the outputs can be directly connected to the speaker in the simplest configuration. This type of filter less design is suitable for portable applications where the speaker is very close to the amplifier. In other words, this is preferable in applications where the length of the traces between the speaker and amplifier is short. The following diagram shows this simple configuration.



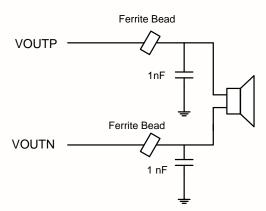
NAU82011WG outputs connected to speaker without filter circuit

#### 7.5 Class D with filter

In some applications, the shorter trace lengths are not possible because of speaker size limitations and other layout reasons. In these applications, the long traces will cause EMI issues. There are two types of filter circuits available to reduce the EMI effects. These are ferrite bead and LC filters.

#### 7.5.1 Ferrite Bead filter

The ferrite bead filters are used to reduce the high frequency emissions. The typical circuit diagram is shown in the figure.



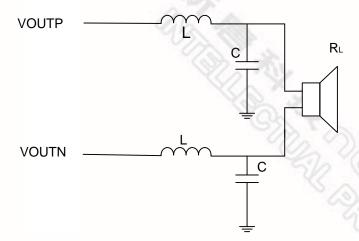
NAU82011WG outputs connected to speaker with Ferrite Bead filter

The characteristic of ferrite bead is such that it offers higher impedance at high frequencies. For better EMI performance select ferrite bead which offers highest impedance at high frequencies, so that it will attenuate the signals at higher frequencies. Usually the ferrite beads have low impedance in the audio range, so it will act as a pass through filter in the audio frequency range.

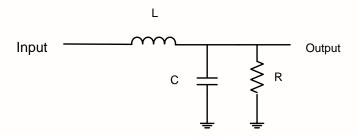


### 7.5.2 LC filter

The LC filter is used to suppress the low frequency emissions. The following diagram shows the NAU82011WG outputs connected to the speaker with LC filter circuit.  $R_L$  is the resistance of the speaker coil.



#### NAU82011WG outputs connected to speaker with LC filter



#### Standard Low pass LCR filter

The following are the equations for the critically damped ( $\zeta = 0.707$ ) standard low pass LCR filter

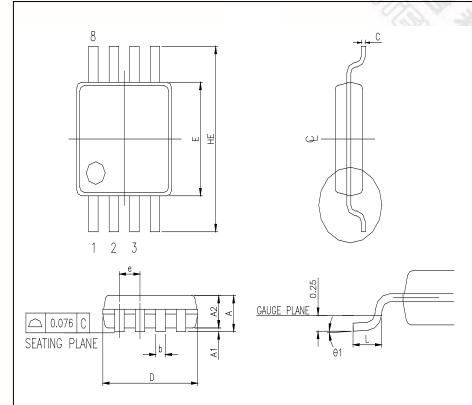
$$2\pi fc = \frac{1}{\sqrt{(LC)}}$$
 fc is the cutoff frequency 
$$\zeta = 0.707 = \frac{1}{2R} * \sqrt{\frac{L}{C}}$$

The L and C values for differential configuration can be calculated by duplicating the single ended configuration values and substituting  $R_L = 2R$ .



# 8 Package Dimensions

# 8.1 8 pin MSOP package



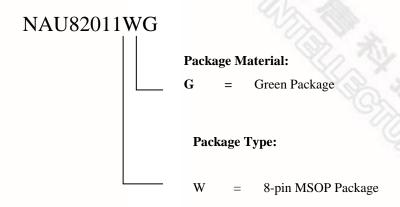
CONTROLLING DIMENSION: MILLIMETERS

CAMBOI	DIME	nsion ii	MM /	DIMENS	SION IN	INCH	
SYMBOL	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А			1.10			0.043	
A1	0.05		0.15	0.002		0.006	
A2	0.81	0.86	0.91	0.032	0.034	0.036	
С	0.13		0.23	0.005		0.009	
b	0.25		0.40	0.0098		0.0157	
D	2.90	3.00	3.10	0.114	0.118	0.122	
E	2.90	3.00	3.10	0.114	0.118	0.122	
HE		4.90 BS	SC .	0.193 BSC			
L	0.445	0.55	0.648	0.0175	0.0217	0.0255	
θ1	0,		6°	0,		6.	
е		0.65 BS	С		0.026 B	SC	



### 9 Ordering Information

Nuvoton Part Number Description



### **Version History**

VERSION	DATE	PAGE	DESCRIPTION
NAU82011WG Datasheet Rev1.0	Dec, 2012	NA	Revision1.0

Table 1: Version History

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